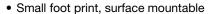


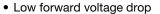
High Performance Schottky Rectifier, 2.1 A



PRODUCT SUMMARY				
Package	SMA			
I _{F(AV)}	2.1 A			
V_{R}	100 V			
V _F at I _F	0.78 V			
I _{RM}	1 mA at 125 °C			
T _J max.	150 °C			
Diode variation	Single die			
E _{AS}	1.0 mJ			

FEATURES







- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-10MQ100NPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	DC	2.1	A		
V _{RRM}		100	V		
I _{FSM}	t _p = 5 μs sine	120	A		
V _F	1.5 A _{pk} , T _J = 125 °C	0.68	V		
T _J	Range	-55 to +150	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-10MQ100NPbF	UNITS	
Maximum DC reverse voltage	V _R	100	V	
Maximum working peak reverse voltage	V_{RWM}	100	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 4	I _{F(AV)}	50 % duty cycle at T _L = 126 °C, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad area)		2.1	А
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	120	Α
non-repetitive surge current, $T_J = 25$ °C I_{FSM} See fig. 6		10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	30	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 0.5 A, L = 8 mH		1.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _B typical		0.5	А

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	1 A	T 05 °C	0.78	V
		1.5 A	T _J = 25 °C	0.85	
		1 A	T _J = 125 °C	0.63	
		1.5 A		0.68	
Maximum reverse leakage current See fig. 2	. (1)	T _J = 25 °C	V _R = Rated V _R	0.1	mA
	I _{RM} ⁽¹⁾	T _J = 125 °C		1	
Threshold voltage	V _{F(TO)}	T _J = T _J maximum		0.52	V
Forward slope resistance	r _t			78.4	mΩ
Typical junction capacitance	C _T	V _R = 10 V _{DC} , T _J = 25 °C, test signal = 1 MHz		38	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{^{(1)}}$ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-55 to +150	°C
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W
Approximate weight			0.07	g
		0.002	OZ.	
Marking device		Case style SMA (similar D-64)	V1	J

Note

$$^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$$

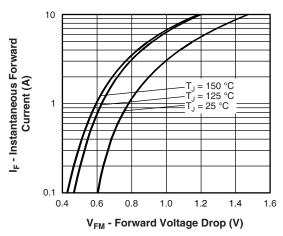


Fig. 1 - Maximum Forward Voltage Drop Characteristics

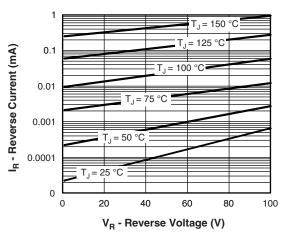


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

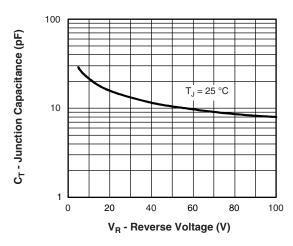


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

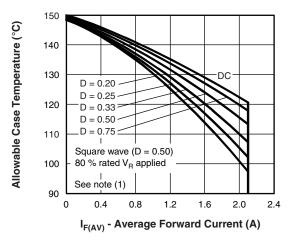


Fig. 4 - Maximum Average Forward Current vs. Allowable Lead Temperature

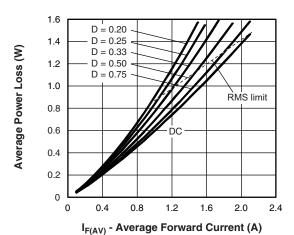


Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current

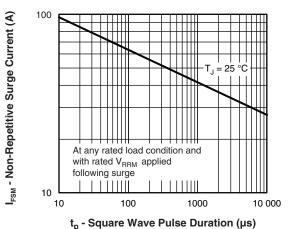


Fig. 6 - Maximum Peak Surge Forward Current vs.
Pulse Duration

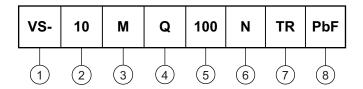
Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = 80 \text{ \% rated } V_R \\ \end{array}$



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating

3 - M = SMA

Q = Schottky "Q" series

- Voltage rating (100 = 100 V)

6 - N = new SMA

7 - • None = box (1000 pieces)

• TR = tape and reel (7500 pieces)

PbF = lead (Pb)-free

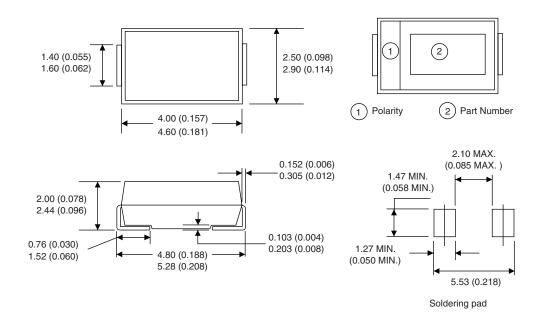
LINKS TO RELATED DOCUMENTS			
Dimensions		www.vishay.com/doc?95018	
Part marking information		www.vishay.com/doc?95029	
Dealersing information	Tape and reel	www.vishay.com/doc?95034	
Packaging information	Bulk	www.vishay.com/doc?95397	
SPICE model		www.vishay.com/doc?95371	



Vishay High Power Products

SMA

DIMENSIONS in millimeters (inches)





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Revision: 02-Oct-12 Document Number: 91000

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